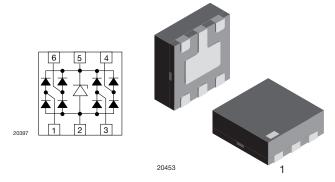


4-Line BUS-Port ESD Protection



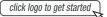
MARKING (example only)



Dot = pin 1 marking XX = date code

YY = type code (see table below)

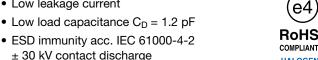
DESIGN SUPPORT TOOLS





FEATURES

- Ultra compact LLP75-6L package
- 4-line USB ESD protection
- · Low leakage current
- ESD immunity acc. IEC 61000-4-2 ± 30 k ± 30 k¹
- High s
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu),
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



V contact discharge	OOMI LIAM
W contact discharge	HALOGEN
V air discharge	FREE
surge current acc. IEC 61000-4-5 $I_{pp} > 11 A$	GREEN (5-2008)
racious motal (a.g. Ag. Au NiPd NiPdAu)	

ORDERING INFORMATION					
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY		
VBUS54CV-HSF	VBUS54CV-HSF-G4-08	3000	15 000		

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
VBUS54CV-HSF	LLP75-6L	UC	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C	

ABSOLUTE MAXIMUM RATINGS VBUS54CV-HSF						
PARAMETER	TEST CONDITIONS	SYMBOL VALUE		UNIT		
Peak pulse current	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t _p = 8/20 μs/single shot	l	11	A		
	Pin 5 to pin 2 acc. IEC 61000-4-5; $t_p = 8/20 \mu s$; single shot	Іррм	13			
Peak pulse power	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t _p = 8/20 μs/single shot	P _{PP}	242	W		
	Pin 5 to pin 2 acc. IEC 61000-4-5; t _p = 8/20 μs; single shot	ГРР	246			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30			
Operating temperature	Junction temperature	T _J	-40 to +125	°C		
Storage temperature		T _{STG}	-40 to +150	°C		

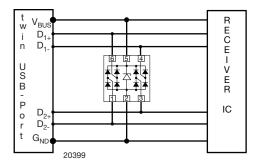


ELECTRICAL CHARACTERISTICS VBUS54CV-HSF (pin 1, 3, 4, or 6 to pin 2) (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	4	lines	
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5.5	V	
Reverse voltage	at I _R = 0.1 μA	V_R	5.5	-	-	V	
Reverse current	at V _{RWM} = 5.5 V	I _R	-	0.01	0.1	μA	
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	7	7.9	8.6	V	
Reverse clamping voltage	at I _{PP} = 11 A	V _C	-	18	22	V	
Forward clamping voltage	at I _{PP} =11 A	V_{F}	-	6.5	8	V	
Capacitance	V_{R} (at I/O pin) = 0 V V_{R} (at pin 5) = 5 V; f = 1 MHz	C _D	-	1.2	2.5	pF	
Line symmetry	Difference of the line capacitances	dC_D	-	-	0.2	pF	

ELECTRICAL CHARACTERISTICS (pin 5 to pin 2) (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5.5	V
Reverse voltage	at $I_R = 0.1 \mu A$; pin 2 to pin 1	V_R	5.5	-	-	V
Reverse current	at V _{RWM} = 5.5 V	I _R	-	0.01	0.1	μΑ
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.3	7.1	8	V
Reverse clamping voltage	at I _{PP} = 13 A	V _C	-	18	22	V
Forward clamping voltage	at I _{PP} =13 A	V _F	-	-	7	V
Capacitance	V _R (at pin 5) = 0 V; f = 1 MHz	C _D	-	190	-	pF

APPLICATION NOTE

With the VBUS54CV-HSF a double, high speed USB-port can be protected against transient voltage signals. Negative transients will be clamped close below the ground level while positive transients will be clamped close above the working range. An avalanche diode clamps the supply line (V_{BUS} at pin 5) to ground (pin 2). The high speed data lines, D_{1+} , D_{2+} , D_{1-} and D_{2-} , are connected to pin 1, 3, 4 and 6. As long as the signal voltage on the data lines is between the ground- and the V_{BUS} -level, the low capacitance PN-diodes offer a very high isolation to V_{BUS} , ground and to the other data lines. But as soon as any transient signal exceeds this working range, one of the PN-diodes gets in the forward mode and clamps the transient to ground or the avalanche break through voltage level.



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

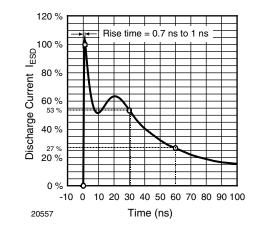


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

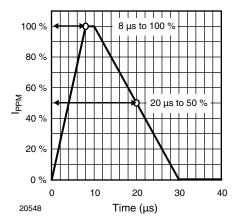


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

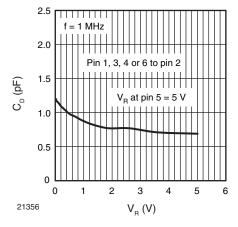


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

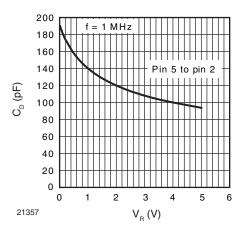


Fig. 4 - Typical Capacitance C_{D} vs. Reverse Voltage V_{R}

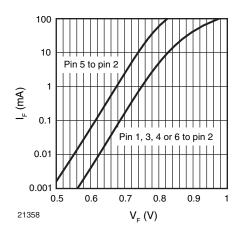


Fig. 5 - Typical Forward Current I_F vs. Forward current I_R

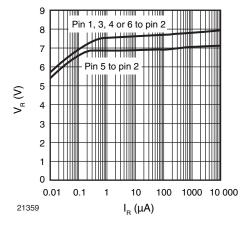


Fig. 6 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

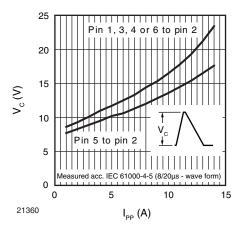


Fig. 7 - Typical Peak Clamping Voltage vs. Peak Pulse Current I_{PP}

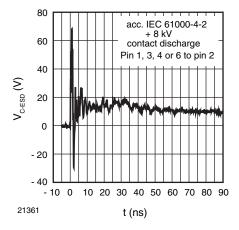


Fig. 8 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

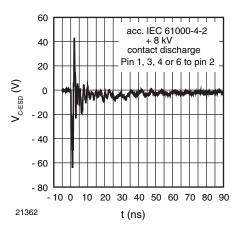


Fig. 9 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

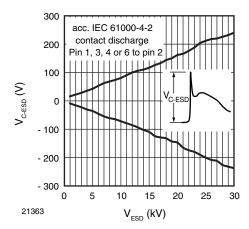
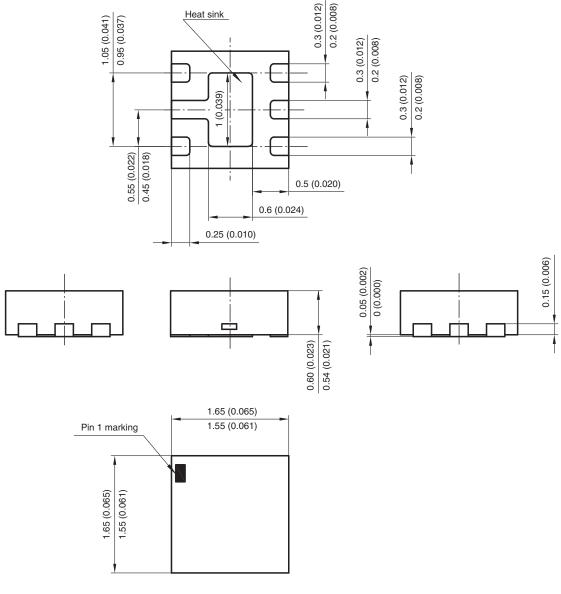
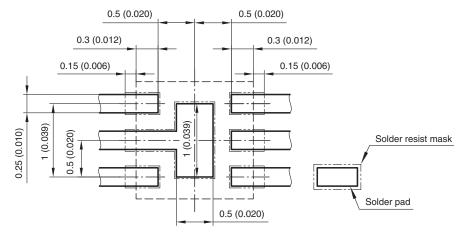


Fig. 10 - Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

PACKAGE DIMENSIONS in millimeters (inches): LLP75-6L



Foot print recommendation:



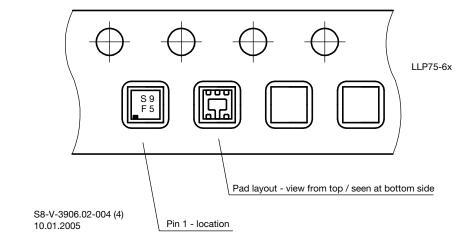
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Rev. 4 - Date: 21. March 2006

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Rev. 1.3, 04-Jan-2019







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